LD-M -S series

Laser type Embedded amplifier photo sensors



Ultra thin beam and high power are achieved at the same time LD-M10R (polarization reflector type)

- Ultra thin laser beam is ideal for detecting minute objects
- Long distance detection up to 15 m is possible (with K-7 reflector)
- Various reflectors available for different detecting distances

LD-S20R (diffuse-reflective)

- Variable-focus spot adjustable down to $\phi 1$
- (In the range of 80-300 mm from light receiving surface)
- Red laser for simple position checking of emitted light spot
 Extra thin laser beam ideal for detection of passage/presence or protrusion of minute objects through gap or small hole



Laser beam employed

Do not look into the beam, do not direct light to human body and follow all instructions for correct and safe use.

Detection method	Detecting distance	Model	Operation mode	Output mode
Polarization reflector type Diffuse- reflective type	The detecting distance depends LD-M10 on the reflector used. LD-M10	LD-M10R	Light-ON/ Dark-ON selectable	NPN open collector
		LD-M10RPN		PNP open collector
	90 ₀ ,200mm	LD-S20R		NPN open collector
	80. 3000	LD-S20RPN	(with Switch)	PNP open collector

Optional Parts

Type

Product name	Model	Detecting distance(m)	Effective reflecting surface (mm)	Purpose/application
	K-15	0.3~7	36×55	For minute object detection
	S-0503A	0.5~7	24×24	For minute object detection
	K-72	1~5	29×8	For minute object detection
Reflector	K-MT4	1~7	35×35	For minute object detection
	K-71	3~5	32×19	When there is restriction to mounting of reflector
	K-7	3~15	56×36	For long distance detection

Select according to the detecting distance of the application and purpose (separately available).

Rating/Performance/Specification

	Туре	NPN output type	PNP output type	NPN output type	PNP output type	
	Model	LD-M10R	LD-M10RPN	LD-S20R	LD-S20RPN	
	Detection method	Polarization	reflector type	Variable-focus	reflective type	
	Spot variable range			80mm - 300mm *3		
	Detecting distance	Depending on reflecto	r (separately available)	30-300mm (10 x 10 mm	white drawing paper) *3	
ance	Power supply		12-24V DC ±10%	/ Ripple 10% max.		
orme	Current consumption	35mA max. *1	40mA max. *1	35mA max. *1	40mA max. *1	
ng/perfc	Output mode	NPN open collector output Sink current 100 mA (30 VDC) max.	PNP open collector output Source current 100 mA (30 VDC) max.	NPN open collector output Sink current 100 mA (30 VDC) max.	PNP open collector output Source current 100 mA (30 VDC) max.	
Ratin	Operation mode		Light-ON/Dark	-ON selectable		
	Anti Interference	Provided				
	Light Emission Stop Function	No-voltage input (contact/non-contact)				
	Response time	0.5ms max.				
	Spot diameter	15 x 7 mm ell	ipse (at 15 m)	ϕ 1mm(adjustable range: 80-300	mm from light receiving surface)	
	Smallest detectable mark width			1 mm (black mark on whit	e background) at 300 mm	
	Light source (wavelength)		Red semiconductor la	aser (650 nm) Class 2		
	Indicator	dicator Operation indicator (red LED) Stability indicator (green LED)			ED)	
_ _	Volume	SENS: sensitivity adjustment				
atior	Switch	Light-ON/Dark-ON selector switch provided				
Cific	Short circuit protection	Provided				
Spec	Connection	Permanently at	Permanently attached cord (outer dimension: dia. 4) 0.2 sq. 4 core 2 m length (black)			
0,	Material	Case: heat-resistant	ABS Lens: Acrylic	Case: heat-resistant ABS Transmitter lens: glass /	Transmitter hood: aluminum / Receiver lens: acrylic	
	Mass	Approx. 80g				
	Accessory	Operation manual, mounting bracket, screwdriver for sensitivity adjustment, warning label, instruction label *2				

*1 Allow sufficient margin in the capacity of the power supply (the laser diode is equipped with a circuit that maintains the same light intensity level by increasing the current if it becomes dark).

*2 The LD-M10 R Series is not provided with a reflector, which is optional.

*3 Distance from the sensor receiving lens surface.

Environmental Specification

	Ambient light	5,000 lx max.	
	Ambient temperature	-10 - +55°C (non-freezing)	
	Ambient humidity	35 - 85%RH (non-condensing)	
nment		LD-M Series: IP67	
		LD-S Series: IP66	
viro	Vibration	10 - 55 Hz / 1.5 mm amplitude / 2 hours each in 3 direction	
Ш	Shook	LD-M series: 500 m/s 2 / 3 times each in 3 directions	
	SHOCK	LD-S series: 300 m/s $^{\scriptscriptstyle 2}$ / 3 times each in 3 directions	
	Dielectric withstanding 1,000 VAC for 1 minute		
	Insulation resistance	500 VDC, 20 M Ω or higher	

Input/Output Circuit and Connection



 The output transistor turns off when load short circuit or overload occurs. Check the load and turn the power back on.

Panel Indication





 Setting within the stable range increases the reliability against variation of environment after setting.

Using Light Emission Stop Function

 Short-circuiting TEST IN PUT (pink) and 0 V (blue) stops the laser light emission at arbitrary timing. When not using the light emission stop function, connect TEST INPUT (pink) to the positive terminal of the power supply (brown).



For Correct Use



•Do not use the product for detection for the protection of human body.

When using the product for safety purposes, ensure safety with the control system as a whole as well as the detection.
 This product is not explosion proof.

- The semiconductor laser used in this product falls under the following class as defined in JIS C 6802 "Safety of Laser Products."
 Class 2 (Emits visible radiation from which the eyes are
 - generally protected by the aversion reactions)
- This product employs a parallel beam of laser and care should be taken not to allow the laser light to enter human eye directly or by specular reflection. Never look into the laser radiation outlet of the transmitter connected to power supply.
- Looking straight into the laser light may damage the eye.
- This product is provided with warning and instruction labels as shown below for notifying and alerting the operator of the sensor of the degree of danger. After the product has been installed, attach the labels in prominent locations on the sensor.

Warning label

ΤΑΚΕΧ



• The radiated laser beam is elliptic due to the characteristics of semiconductor laser. In addition, diffraction pattern is generated due to optical diffraction phenomenon.



- Be notified that this product uses semiconductor laser and is prone to deterioration due to surge current or static electricity.
- The laser diode is equipped with a circuit that maintains the same light intensity level by increasing the current if it becomes dark. For this reason, allow sufficient margin in the capacity of the power supply.
- Always avoid use in which the power is turned on and off consecutively.
- Be sure to turn off the power before moving including mounting and removing or repairing.
- Follow the notes on safety and handling in the operation manual provided for correct use.

Sample Applications

LD-M10R Series Detection of position of vehicle in multilevel parking garage





Detection of displaced cassettes



Setting/adjustment

1) Arrange the sensor face-to-face and in line with the reflector. Swivel the sensor vertically and horizontally with reference to the reflector, use the operation indicator (red LED) to check the area in which the sensor is activated and install the sensor at the center of the area. Make sure that the stability indicator (green LED) is illuminated.

2) Use the sensitivity adjustment volume for fine-tuning when detecting thin rod-like or small objects.

(Note)

Light reflected on the object may be detected depending on the object such as glossy detection objects including stainless steel. In this case, use the sensitivity adjustment volume to prevent detection of light from the object.



LD-S20R Series



Spot position adjustment for variable-focus type sensor



- The spot position is variable between 80 and 300 mm from the light receiving surface.
- The factory setting makes the spot diameter smallest at 300 mm from the light receiving surface. For adjusting the spot position, make sure that there is no obstacle especially in front of the receiver lens and follow the procedure below:
- 1) For viewing the spot, place a white piece of paper in front of the detection object. (Never look into the laser radiation outlet.)
- 2) (With the locking ring tightened,) turn the lens ring for adjusting the spot diameter and position while monitoring the spot on the white paper. In the figure above, turning in the direction A brings the spot position closer to the sensor.

The lens ring is designed to require a certain amount of force to turn for preventing loosening, which may be felt when turning the lens.

- 3) When adjusting for a short distance, loosen the locking ring a little, make adjustment as described above and securely tighten the locking ring.
- 4) After the adjustment, mount and secure the sensor body again.

Characteristics (Typical Example)



LD-M10R series Distance-output characteristics With K-7 reflector 100 (times) gain 10 Excess (Operation level 25 30 Distance (m) 0 5 10 15 20

300

200

LD-S20R series Directional characteristics 400

Distance (m)



LD-S20R series Directional characteristics 400

















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Optional Parts (in mm)

Reflector model	K-7	K-15	K-MT4	K-71	K-72	S-0503A
Detecting distance	3~15m	0.3~7m	1~7m	3~5m	1~5m	0.5~7m
Effective reflecting surface	56×36mm	36×55mm	35×35mm	32×19mm	29×8mm	24×24mm
Dimensions (in mm)			$\begin{array}{c} & 42 \\ \hline \\ 52 \\ \hline \\ 0 \\ \hline \\ 30 \end{array}$			

LDseries

Laser type Embedded amplifier photo sensors



📕 Туре

• Thin red laser beam allows highlyaccurate detection

- Minute object detected at long distance
- Wide variety of models for different detecting distances and detection objects
- Simple adjustment with red spot
- Class 1 and 2 models available

• Reflective type (LD-S33R)

- 0.5 mm mark detected at long distance of 300 mm
- Small-field beam allowing detection through gaps and small holes
- Light emission stop function provided

Take safety measures according to the operation manual.

Detection method	Detecting distance	Model	Detection object	Operation mode	Output mode
	20m	LD-T20R	Opaque objects of ϕ 20 mm or larger		Open
	15m	LD-T20R-P2	Opaque objects of $\phi 2 \text{ mm or larger}$	Light-ON/	
	7 m	LD-T20R-P1	Opaque objects of ϕ 1 mm or larger		
Through- beam type	3 m	LD-T20R-P05	Opaque objects of ϕ 0.5 mm or larger		
	0.7m	LD-T20R-P03	Opaque objects of _0.3 mm or larger		collector
	20m	LD-T20R-C1	Opaque objects of _20 mm or larger	selectable	
	10m	LD-T20R-C1-P2	Opaque objects of _2 mm or larger	(with switch)	
	5m	LD-T20R-C1-P1	Opaque objects of _1 mm or larger		
Limited reflection type	200~400mm	LD-S33R	0.5mm min. (black mark on white background) Detecting distance 300mm		NPN open collector output

PNP output type

PNP output types are available for all models.

PNP output type models are identified by "PN" at the end of model number.

The rating/performance other than the output is the same as those of NPN types.

Optional parts

Туре	Model	Applicable model	Shape, etc.
Cord with M8 connector	FBC-4R2S	For M9 connector type	Straight with 4-core cord of 2 m (transmitter/receiver)
	FBC-4R2L		Angled with 4-core cord of 2 m (transmitter/receiver)
Protective cover	G-MTB2	For through-beam LD-T20R	Rigid protective cover doubling as mounting bracket. See "Dimensions (optional parts)."

	hating/renormance/specification					
	Model	NPN type	LD-T20R	LD-T20R-C1	LD-S33R	
	wouer	PNP type	LD-T20RPN	LD-T20RPN-C1		
	Detection method		Through-t	beam type	Limited reflection type	
	Power	supply	1	2 - 24V DC ±10% / Ripple 10% max	ζ.	
e	Current	NPN type	Transmitter: 20 mA max.	. Receiver: 20 mA max.	38mA以下	
nan	consumption	PNP type	Transmitter: 20 mA max.	. Receiver: 25 mA max.		
perform		Control	NPN open collector output Rating:	sink current 100 mA (30 VDC) max.	NPN open collector 2 outputs Rating: sink current 100 mA (30 VDC) max.	
ating	Output mode	output	PNP open collector output Rating: se	ource current 100 mA (30 VDC) max.		
Ва		Stability	NPN open collector output Rating:	sink current 50 mA (30 VDC) max.		
		output	PNP open collector output Rating: s	source current 50 mA (30 VDC) max.		
	Operation mode Light-ON/Dark-ON select					
	Response time			0.5ms max.		
	Operating angle		30° (at r	receiver)		
	Spot diameter					
	Smallest detectable mark width				0.5 mm (black mark on white background) at 300 mm	
	Light source (light wavelength)		Red semiconductor laser (650 nm) Class 2	Red semiconductor laser (650 nm) Class 1	Red semiconductor laser (650 nm) Class 2	
	Indicator		Transmitter: power indicator (green LED)		Operation indicator (red LED) Stability indicator (green LED)	
			Receiver: operation indicator (red LED) Stability indicator (green LED)			
_	Volu	ume	SENS: sensitivity adj	ustment (at receiver)	8-turn sensitivity adjustment	
atior	Sw	itch	Ligh	nt-ON/Dark-ON selector switch provi	ded	
Cific	Short circuit protection Provided (for control output only)		ntrol output only)	Provided		
Spec	Material	Case	Polya	Body: zinc die-cast / Aluminum head: heat- resistant ABS / Display: polycarbonate		
		Lens	Acr	ylic	Glass	
	Connection Transmitter: 0.3		Permanently attached cord Transmitter: 0.3 sq. 2 core 2 m length (gray)	l(outer dimension: dia. 4.2) Receiver: 0.2 sq. 4 core 2 m length (black)	Permanently attached cord (outer dimension: dia. 4.5) 0.2 sq. 5 core 2 m length	
			-J type: M8 conn	ector connection		
	Ma	ISS	Permanently attached cord type: about 80 g (transmitt	ter/receiver) / -J type: about 25 g (transmitter/receiver)	Approx. 300g	
	Notes		Mounting brack	et, operation manual, warning label,	instruction label	

Bating/Performance/Specification

Environmental Specification

		LD-T20R	LD-S33R	
	Ambient light	5,000 lx max.	Sunlight: Light receiving surface illumination 10,000 max. Incandescent lamp: receiving surface illumination 3,000 lx max.	
ent	Ambient temperature	-10	+55°C	
nme	Ambient humidity	35 - 85%RH		
viro	Protective structure	IP67	IP66	
Ш	Vibration	10 - 55 Hz / 1.5 mm amplitude / 2 hours each in 3 directio		
	Shock	500 m/s 2 / 3 times each in 3 directions	100 m/s ² / 3 times each in 3 directions	
	Dielectric withstanding	1,000 VAC for 1 minute		
	Insulation resistance	500 VDC, 20 MΩ or higher		

• Applicable power supply unit PS Series High capacity of 200 mA at 12 VDC



(General-purpose type) PS3N PS3N-SR PS3F (Multifunctional type) PS3F-SR



- The output transistor turns off when load short circuit or overload occurs. Check the load and turn the power back on.
- The stability output is not provided with short circuit protection.

Switching between Light-ON and Dark-ON The operation mode selector switch is provided on the receiver.

Turn to L for Light-ON mode and D for Dark-ON mode.

Light-ON mode





Dark-ON mode

M8 connector type (-J)



The colors show lead colors for use in combination with the optional cord with M8 connector.

(Transmitter)

Lines other than Lines 1 (brown) and 3 (blue) are unused.

Stability output

The stability output can be used to check for reduction of the light intensity level along with any change in the operating environment or operation over time or to perform initial check of the operation. When two consecutive detections have occurred with the intensity of light detected exceeding the operation level but not reaching 120 % of the level (range allowing stable operation), the stability signal is output when the control output is deactivated.



Characteristics (Typical Example)

• Directional characteristics





• Temperature characteristics





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Input/Output Circuit and Connection LD-S33R



Slow starter circuit is provided for laser emission. The laser light is illuminated about 0.5 seconds after power-up or reset of short circuit caused by emission stop input.

The output transistor turns off when load short circuit or overload occurs. Check the load and turn the power back on.



Using Light Emission Stop Function (LD-S33R only)



Short-circuiting the blue and pink leads of the transmitter stops the laser light emission at arbitrary timing.

Activation Area Characteristics (Typical Example) LD-S33R



Sample Applications Highly-accurate detection achieved with extra thin beam





Detection of marks on corrugated cardboard boxes through narrow gap





For Correct Use



ΤΑΚΕΧ

Do not use the product for for the protection of human body.

•When using the product for safety purposes, ensure "System-Wide" safety with the control system as a whole as well as the detection. •This product is not explosion proof.

- The semiconductor laser used in this product falls under the following class as defined in JIS C 6802 "Safety of Laser Products."
 Class 1 (Intrinsically safe under the rationally predictable operation conditions)
 - •Class 2 (Emits visible radiation from which the eyes are generally protected by the aversion reactions)
- This product employs a parallel beam of laser and care should be taken not to allow the laser light to enter human eye. Never look into the laser radiation outlet of the transmitter connected to power supply. Looking straight into the laser light may damage the eye.
- This product is provided with warning and instruction labels as shown below for notifying and alerting the operator of the sensor of the degree of danger. After the product has been installed, attach the labels in prominent locations on the sensor.



• The radiated laser beam is elliptic due to the characteristics of semiconductor laser. In addition, diffraction pattern is generated due to optical diffraction phenomenon.



- Be notified that this product uses semiconductor laser and is prone to deterioration due to surge current or static electricity.
- The laser diode is equipped with a circuit that maintains the same light intensity level by increasing the current if it becomes dark. For this reason, allow sufficient margin in the capacity of the power supply.
- Always avoid use in which the power is turned on and off consecutively.
- Be sure to turn off the power before moving including mounting and removing or repairing.



Dimensions (Optional parts) (in mm)

With mounting bracket attached

12

59



2